MoS₂ Coating Facilitating Delayed Activation and Fast Charge-Discharge properties in Highly-Doped n-type SiNW Anodes for Lithium-Ion Batteries

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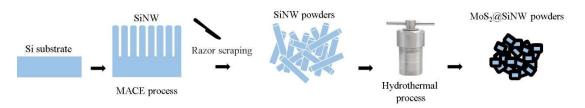


Fig. 1: The manufacturing scheme illustrates the formation of Silicon nanowires and the synthesis of MoS₂@SiNW powder. The precursor for hydrothermal process consists of oxalic acid, NaMoO₄, Thiourea and DI water.

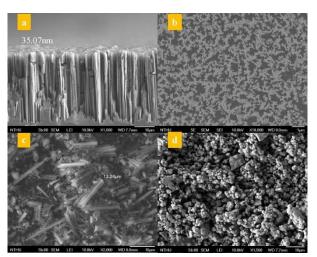


Fig. 2: Morphology of SiNW and MoS₂@SiNW. (a) Side view (scale bar: 10 um) and (b) Top view (scale bar: 1 um) of SiNW. (c) SiNW powder (scale bar: 10 um) and (d) MoS₂@SiNW powder (scale bar: 10 um)

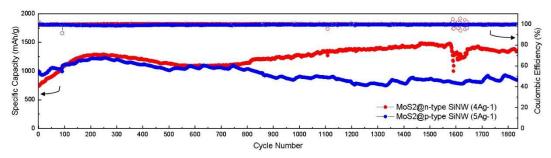


Fig. 3: Cycling performance of $MoS_2@n$ -type SiNW and $MoS_2@p$ -type SiNW anodes was measured at current densities of 4 A g⁻¹ and 5 A g⁻¹ each for around 1800 cycles.

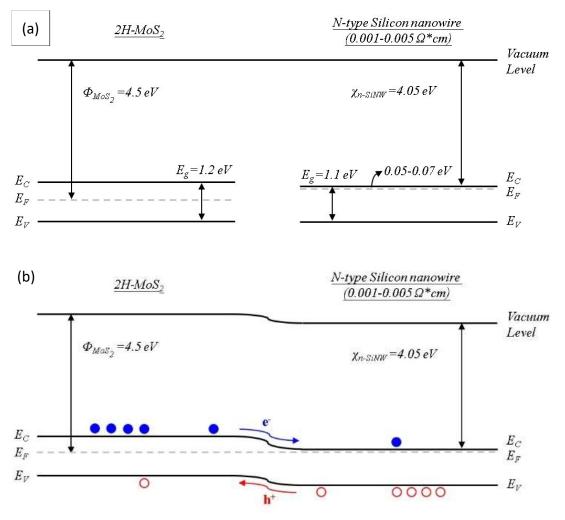


Fig. 4: (a) Band diagram of MoS2@n-type SiNW (b) Band bending diagram of MoS2@n-SiNW